HT12A/HT12E
2^{12} Series of Encoders

Features

- Operating voltage
  - 2.4V~5V for the HT12A
  - 2.4V~12V for the HT12E
- Low power and high noise immunity CMOS technology
- Low standby current: $0.1\mu A$ (typ.) at V_{DD}=5V
- HT12A with a 38kHz carrier for infrared transmission medium

- Minimum transmission word
  - Four words for the HT12E
  - One word for the HT12A
- Built-in oscillator needs only 5% resistor
- Data code has positive polarity
- Minimal external components
- Pair with Holtek's 2^{12} series of decoders
- 18-pin DIP, 20-pin SOP package

Applications

- Burglar alarm system
- Smoke and fire alarm system
- Garage door controllers
- Car door controllers

- Car alarm system
- Security system
- Cordless telephones
- Other remote control systems

General Description

The 2^{12} encoders are a series of CMOS LSIs for remote control system applications. They are capable of encoding information which consists of N address bits and 12−N data bits. Each address/data input can be set to one of the two logic states. The programmed addresses/data are transmitted together with the header bits via an RF or an infrared transmission medium upon receipt of a trigger signal. The capability to select a $\overline{TE}$ trigger on the HT12E or a DATA trigger on the HT12A further enhances the application flexibility of the 2^{12} series of encoders. The HT12A additionally provides a 38kHz carrier for infrared systems.

Selection Table

Function \\ Part No.	Address No.	Address/ Data No.	Data No.	Oscillator	Trigger	Carrier Output	Negative Polarity	Package
HT12A	8	0	4	455kHz resonator	D8~D11	38kHz	No	18DIP, 20SOP
HT12E	8	4	0	RC oscillator	$\overline{TE}$	No	No	18DIP, 20SOP

Note: Address/Data represents pins that can be either address or data according to the application requirement.
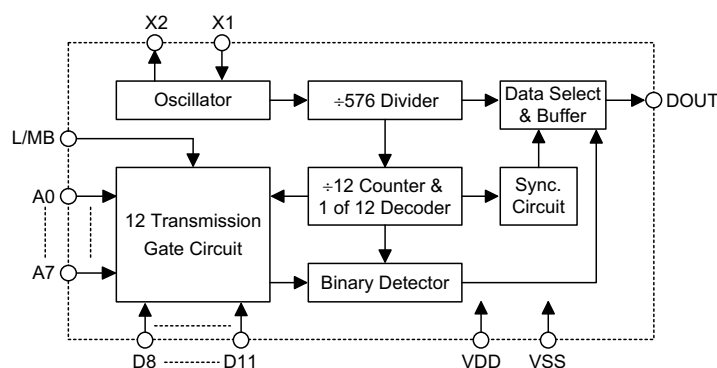
Block Diagram

$\overline{\text{TE}}$ Trigger
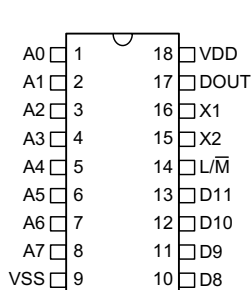
HT12E
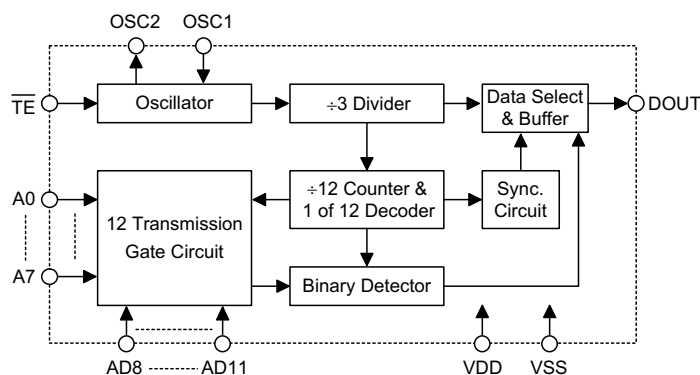
DATA Trigger

HT12A

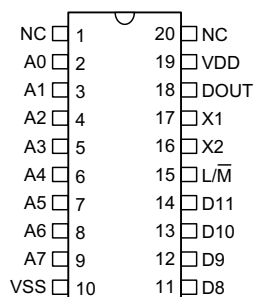Note: The address data pins are available in various combinations (refer to the address/data table).
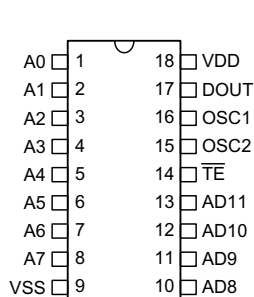
Pin Assignment

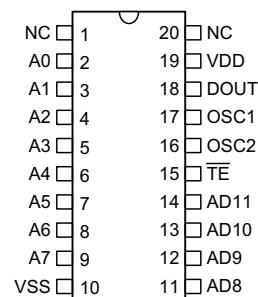**8-Address 4-Data**

HT12A −18 DIP-A

8-Address 4-Data

HT12A −20 SOP-A

8-Address 4-Address/Data


HT12E −18 DIP-A

8-Address 4-Address/Data

HT12E − 20 SOP-A

Pin Description

Pin Name	I/O	Internal Connection	Description
A0~A7	I	CMOS IN Pull-high (HT12A)	Input pins for address A0~A7 setting These pins can be externally set to VSS or left open
		NMOS TRANSMISSION GATE PROTECTION DIODE (HT12E)	
AD8~AD11	I	NMOS TRANSMISSION GATE PROTECTION DIODE (HT12E)	Input pins for address/data AD8~AD11 setting These pins can be externally set to VSS or left open
D8~D11	I	CMOS IN Pull-high	Input pins for data D8~D11 setting and transmission enable, active low These pins should be externally set to VSS or left open (see Note)
DOUT	O	CMOS OUT	Encoder data serial transmission output
L/$\overline{M}$	I	CMOS IN Pull-high	Latch/Momentary transmission format selection pin: Latch: Floating or VDD Momentary: VSS
$\overline{TE}$	I	CMOS IN Pull-high	Transmission enable, active low (see Note)
OSC1	I	OSCILLATOR 1	Oscillator input pin
OSC2	O	OSCILLATOR 1	Oscillator output pin
X1	I	OSCILLATOR 2	455kHz resonator oscillator input
X2	O	OSCILLATOR 2	455kHz resonator oscillator output
VSS	I	—	Negative power supply, ground
VDD	I	—	Positive power supply

Note: D8~D11 are all data input and transmission enable pins of the HT12A.

$\overline{TE}$ is a transmission enable pin of the HT12E.

Approximate Internal Connections
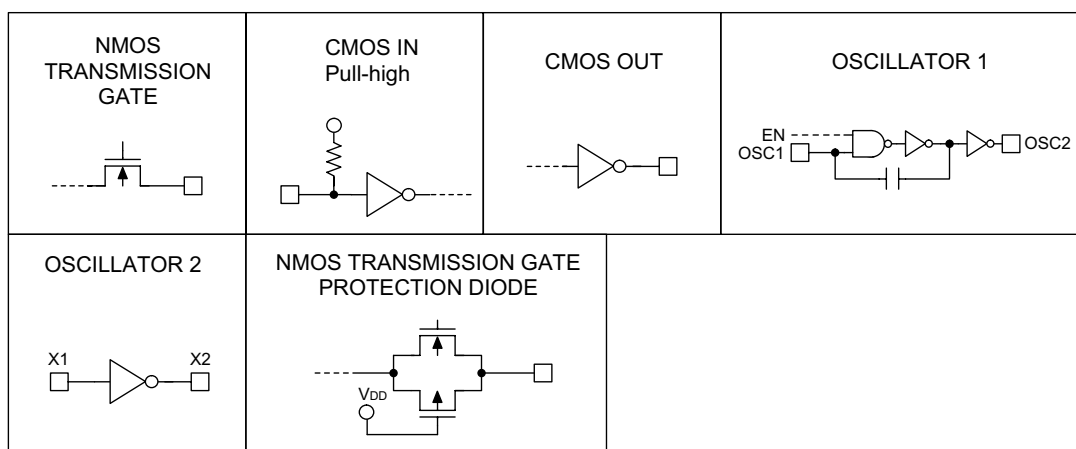
Absolute Maximum Ratings

Supply Voltage (HT12A) ....V_{SS}–0.3V to V_{SS}+5.5V

Input Voltage ....V_{SS}–0.3 to V_{DD}+0.3V

Operating Temperature...........................–20°C to 75°C

Supply Voltage (HT12E) ....–0.3V to 13V

Storage Temperature............................–50°C to 125°C

Note: These are stress ratings only. Stresses exceeding the range specified under "Absolute Maximum Ratings" may cause substantial damage to the device. Functional operation of this device at other conditions beyond those listed in the specification is not implied and prolonged exposure to extreme conditions may affect device reliability.

Electrical Characteristics

HT12A   Ta=25°C

Symbol	Parameter	Test Conditions		Min.	Typ.	Max.	Unit
		V_{DD}	Conditions				
V_{DD}	Operating Voltage	—	—	2.4	3	5	V
I_{STB}	Standby Current	3V	Oscillator stops	—	0.1	1	μA
		5V		—	0.1	1	μA
I_{DD}	Operating Current	3V	No load f_{OSC}=455kHz	—	200	400	μA
		5V		—	400	800	μA
I_{DOUT}	Output Drive Current	5V	V_{OH}=0.9V_{DD} (Source)	–1	–1.6	—	mA
			V_{OL}=0.1V_{DD} (Sink)	2	3.2	—	mA
V_{IH}	"H" Input Voltage	—	—	0.8V_{DD}	—	V_{DD}	V
V_{IL}	"L" Input Voltage	—	—	0	—	0.2V_{DD}	V
R_{DATA}	D8~D11 Pull-high Resistance	5V	V_{DATA}=0V	—	150	300	kΩ

HT12E   Ta=25°C

| Symbol	Parameter	Test Conditions		Min.	Typ.	Max.	Unit
		V_{DD}	Conditions				
V_{DD}	Operating Voltage	—	—	2.4	5	12	V
I_{STB}	Standby Current	3V	Oscillator stops	—	0.1	1	μA
		12V		—	2	4	μA
I_{DD}	Operating Current	3V	No load, f_{OSC}=3kHz	—	40	80	μA
		12V		—	150	300	μA
I_{DOUT}	Output Drive Current	5V	V_{OH}=0.9V_{DD} (Source)	–1	–1.6	—	mA
			V_{OL}=0.1V_{DD} (Sink)	1	1.6	—	mA
V_{IH}	"H" Input Voltage	—	—	0.8V_{DD}	—	V_{DD}	V
V_{IL}	"L" Input Voltage	—	—	0	—	0.2V_{DD}	V
f_{OSC}	Oscillator Frequency	5V	R_{OSC}=1.1MΩ	—	3	—	kHz
$R_{\overline{TE}}$	$\overline{TE}$ Pull-high Resistance	5V	$V_{\overline{TE}}$=0V	—	1.5	3	MΩ

Functional Description

Operation

The 2^{12} series of encoders begin a 4-word transmission cycle upon receipt of a transmission enable ($\overline{TE}$ for the HT12E or D8~D11 for the HT12A, active low). This cycle will repeat itself as long as the transmission enable ($\overline{TE}$ or D8~D11) is held low. Once the transmission enable returns high the encoder output completes its final cycle and then stops as shown below.
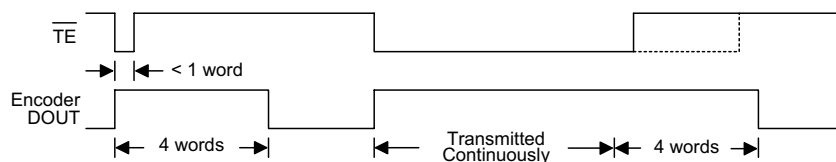
Transmission timing for the HT12E
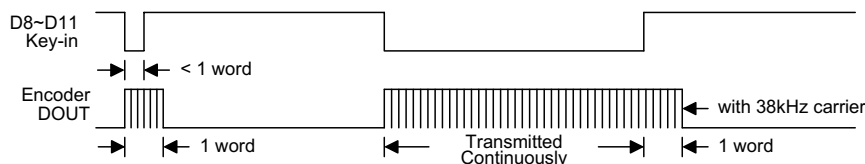
Transmission timing for the HT12A (L/$\overline{M}$=Floating or VDD)
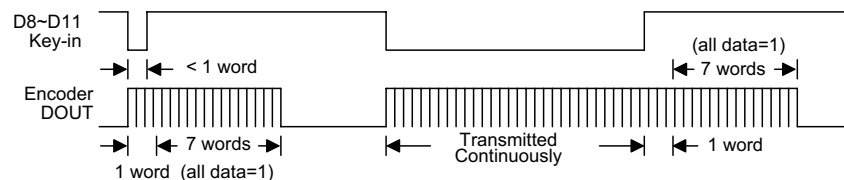
Transmission timing for the HT12A (L/$\overline{M}$=VSS)

Information Word

If L/$\overline{M}$=1 the device is in the latch mode (for use with the latch type of data decoders). When the transmission enable is removed during a transmission, the DOUT pin outputs a complete word and then stops. On the other hand, if L/$\overline{M}$=0 the device is in the momentary mode (for use with the momentary type of data decoders). When the transmission enable is removed during a transmission, the DOUT outputs a complete word and then adds 7 words all with the ″1″ data code.
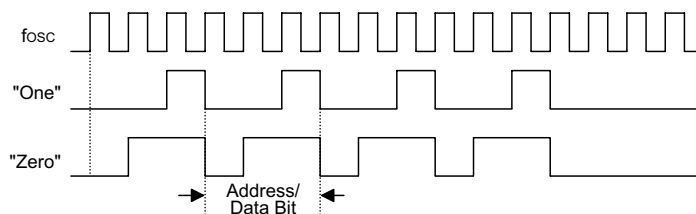
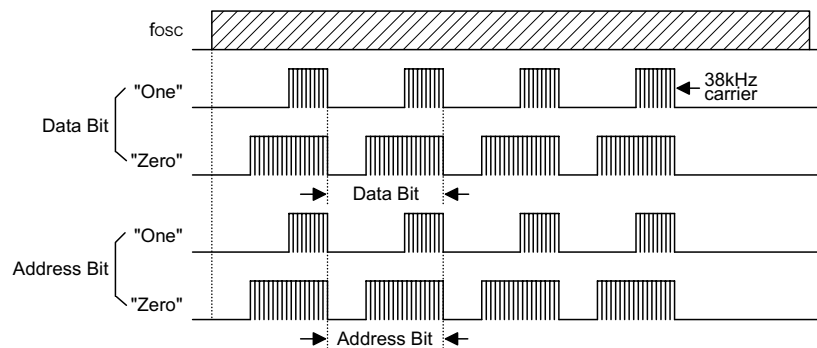An information word consists of 4 periods as illustrated below.
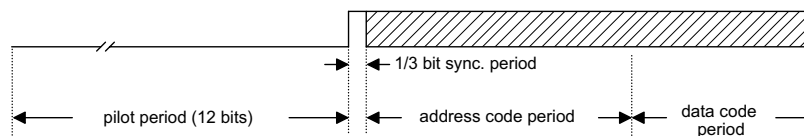
Composition of information

Address/Data Waveform

Each programmable address/data pin can be externally set to one of the following two logic states as shown below.

Address/Data bit waveform for the HT12E

Address/Data bit waveform for the HT12A

The address/data bits of the HT12A are transmitted with a 38kHz carrier for infrared remote controller flexibility.

Address/Data Programming (Preset)

The status of each address/data pin can be individually pre-set to logic ″high″ or ″low″. If a transmission-enable signal is applied, the encoder scans and transmits the status of the 12 bits of address/data serially in the order A0 to AD11 for the HT12E encoder and A0 to D11 for the HT12A encoder.

During information transmission these bits are transmitted with a preceding synchronization bit. If the trigger signal is not applied, the chip enters the standby mode and consumes a reduced current of less than 1μA for a supply voltage of 5V.

Usual applications preset the address pins with individual security codes using DIP switches or PCB wiring, while the data is selected by push buttons or electronic switches.

The following figure shows an application using the HT12E:
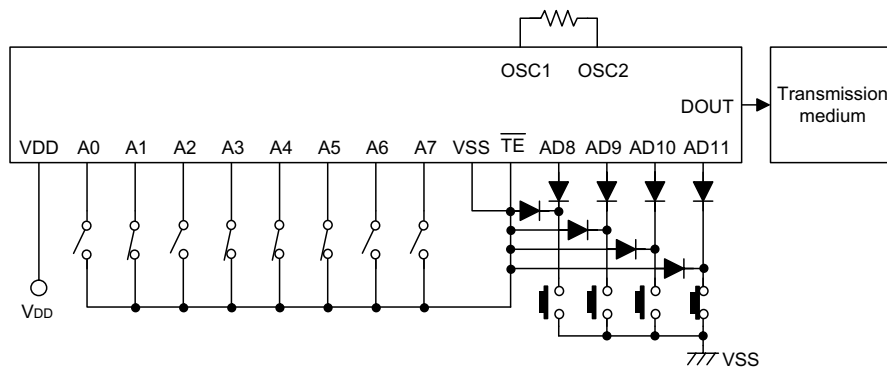
The transmitted information is as shown:

Pilot & Sync.	A0	A1	A2	A3	A4	A5	A6	A7	AD8	AD9	AD10	AD11
	1	0	1	0	0	0	1	1	1	1	1	0

Address/Data Sequence

The following provides the address/data sequence table for various models of the 2^{12} series of encoders.

Part No.	Address/Data Bits											
	0	1	2	3	4	5	6	7	8	9	10	11
HT12A	A0	A1	A2	A3	A4	A5	A6	A7	D8	D9	D10	D11
HT12E	A0	A1	A2	A3	A4	A5	A6	A7	AD8	AD9	AD10	AD11

Transmission Enable

For the HT12E encoders, transmission is enabled by applying a low signal to the $\overline{TE}$ pin. For the HT12A encoders, transmission is enabled by applying a low signal to one of the data pins D8~D11.

Two Erroneous HT12E Application Circuits

The HT12E must follow closely the application circuits provided by Holtek (see the ″Application circuits″).

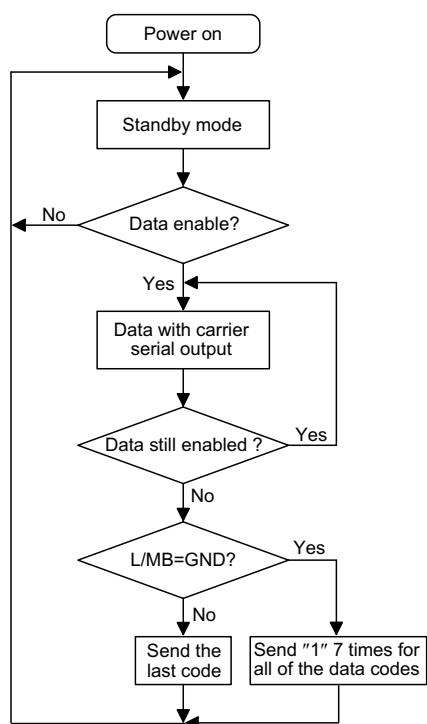• Error: AD8~AD11 pins input voltage > V_{DD}+0.3V
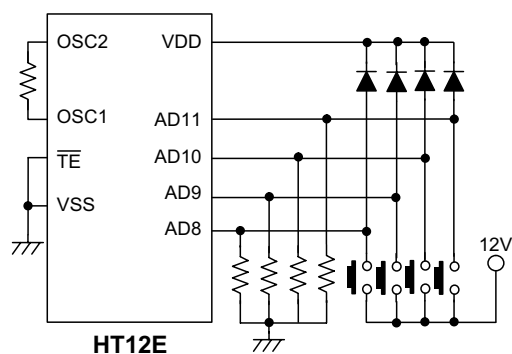
HT12E

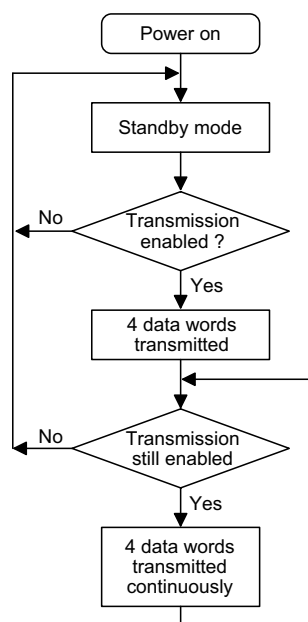• Error: The IC′s power source is activated by pins AD8~AD11
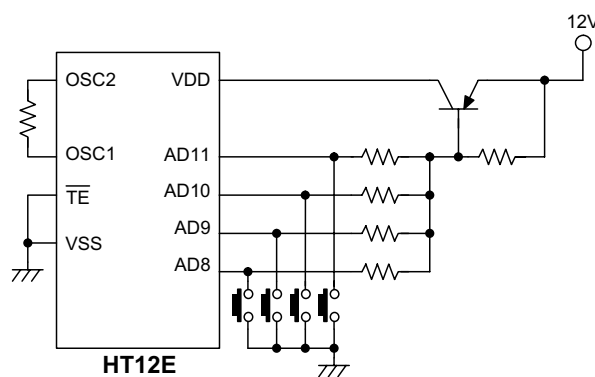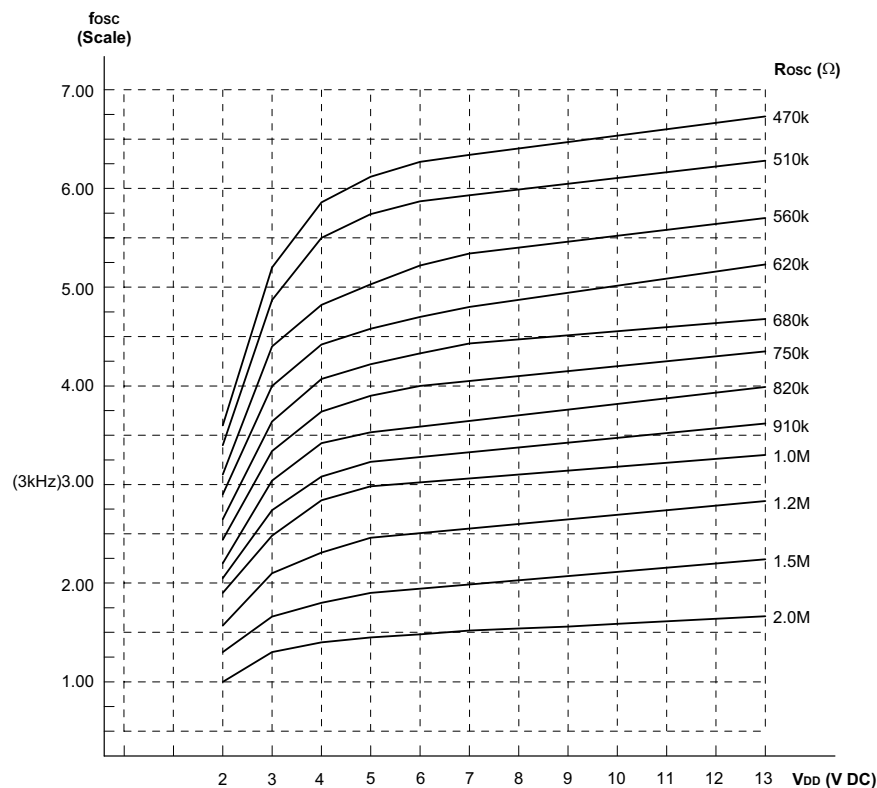

HT12E

Flowchart

• HT12A

• HT12E
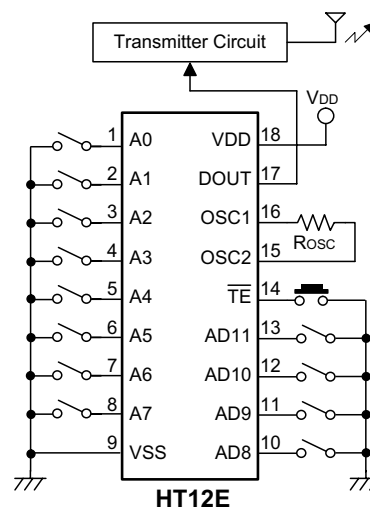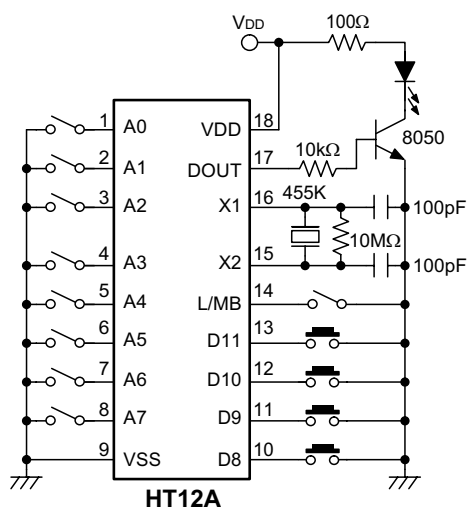

Note: D8~D11 are transmission enables of the HT12A.
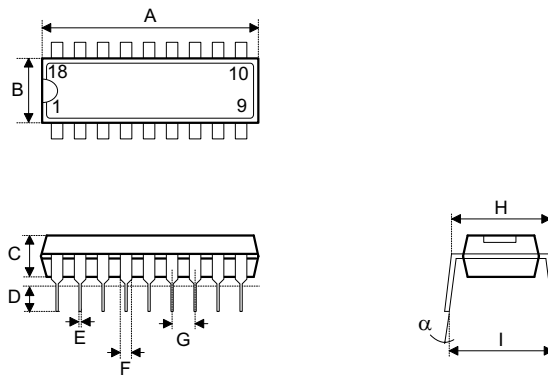
$\overline{TE}$ is the transmission enable of the HT12E.

Oscillator Frequency vs. Supply Voltage

The recommended oscillator frequency is f_{OSCD} (decoder) $\cong 50\ f_{OSCE}$ (HT12E encoder)

$$\cong \frac{1}{3} f_{OSCE} \text{ (HT12A encoder)}$$

Application Circuits

HT12A

HT12E

Package Information
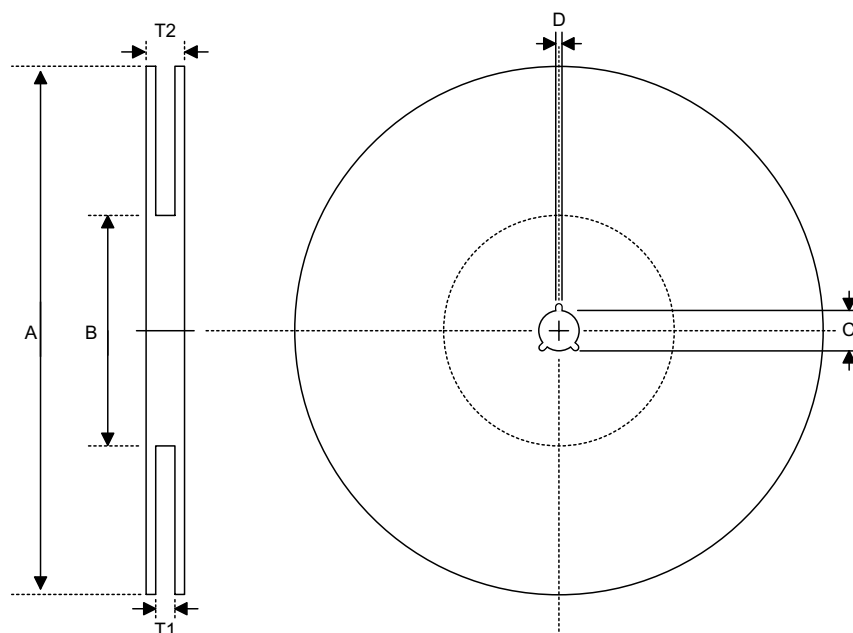
18-pin DIP (300mil) Outline Dimensions

Symbol	Dimensions in mil		
	Min.	**Nom.**	**Max.**
A	895	—	915
B	240	—	260
C	125	—	135
D	125	—	145
E	16	—	20
F	50	—	70
G	—	100	—
H	295	—	315
I	335	—	375
α	0°	—	15°

20-pin SOP (300mil) Outline Dimensions
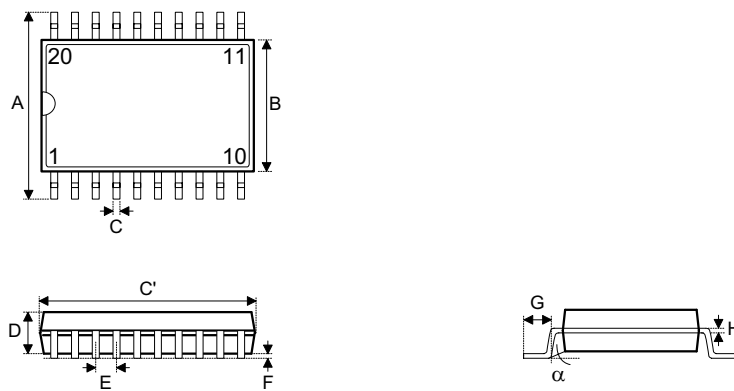
Symbol	Dimensions in mil		
	Min.	**Nom.**	**Max.**
A	394	—	419
B	290	—	300
C	14	—	20
C′	490	—	510
D	92	—	104
E	—	50	—
F	4	—	—
G	32	—	38
H	4	—	12
α	0°	—	10°

Product Tape and Reel Specifications

Reel Dimensions

SOP 20W

Symbol	Description	Dimensions in mm
A	Reel Outer Diameter	330±1.0
B	Reel Inner Diameter	62±1.5
C	Spindle Hole Diameter	13.0+0.5 −0.2
D	Key Slit Width	2.0±0.5
T1	Space Between Flange	24.8+0.3 −0.2
T2	Reel Thickness	30.2±0.2

Carrier Tape Dimensions
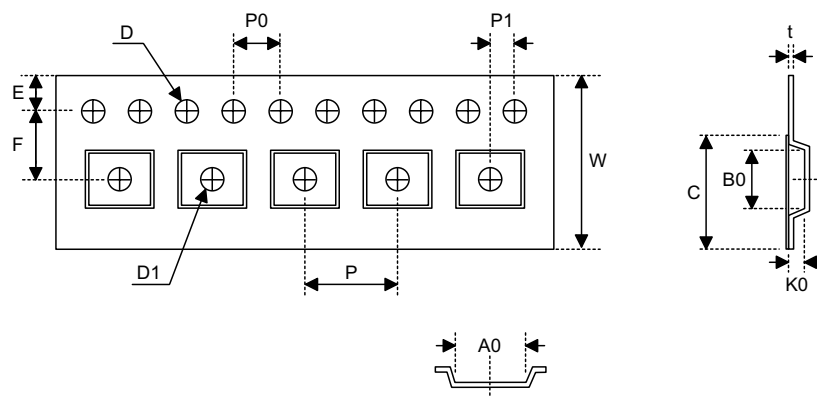
SOP 20W

Symbol	Description	Dimensions in mm
W	Carrier Tape Width	24.0+0.3 −0.1
P	Cavity Pitch	12.0±0.1
E	Perforation Position	1.75±0.1
F	Cavity to Perforation (Width Direction)	11.5±0.1
D	Perforation Diameter	1.5+0.1
D1	Cavity Hole Diameter	1.5+0.25
P0	Perforation Pitch	4.0±0.1
P1	Cavity to Perforation (Length Direction)	2.0±0.1
A0	Cavity Length	10.8±0.1
B0	Cavity Width	13.3±0.1
K0	Cavity Depth	3.2±0.1
t	Carrier Tape Thickness	0.3±0.05
C	Cover Tape Width	21.3

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